2SB1548, 2SB1548A

Silicon PNP epitaxial planar type

For power amplification

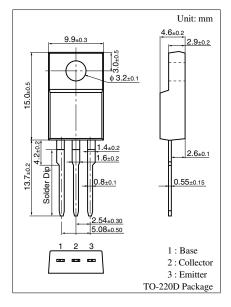
Complementary to 2SD2374 and 2SD2374A

Features

- \bullet High forward current transfer ratio h_{FE} which has satisfactory linearity
- \bullet Low collector to emitter saturation voltage $V_{\mbox{CE(sat)}}$
- Full-pack package which can be installed to the heat sink with one screw

Absolute Maximum Hatings $T_{\rm C} = 25$ C								
Parameter		Symbol	Rating	Unit				
Collector to base	2SB1548	V _{CBO}	-60	V				
voltage	2SB1548A		-80					
Collector to	2SB1548	V _{CEO}	-60	V				
emitter voltage	2SB1548A		-80					
Emitter to base voltage		V _{EBO}	-5	V				
Peak collector current		I _{CP}	-5	А				
Collector current		I _C	-3	А				
Collector power	$T_C = 25^{\circ}C$	P _C	25	W				
dissipation	$T_a = 25^{\circ}C$		2					
Junction temperature		Tj	150	°C				
Storage temperature		T _{stg}	-55 to +150	°C				

Absolute Maximum Ratings $T_C = 25^{\circ}C$



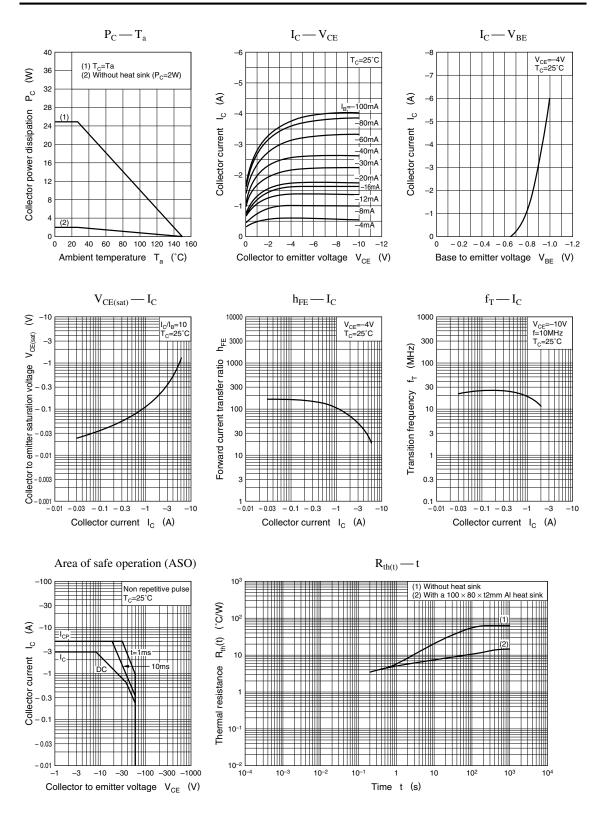
Electrical Characteristics $T_C = 25^{\circ}C$

Paramete	r	Symbol	Conditions	Min	Тур	Max	Unit
Collector cutoff	2SB1548	I _{CES}	$V_{CE} = -60 \text{ V}, V_{BE} = 0$			-200	μΑ
current	2SB1548A		$V_{CE} = -80 \text{ V}, V_{BE} = 0$			-200	
Collector cutoff	2SB1548	I _{CEO}	$V_{CE} = -30 \text{ V}, I_B = 0$			-300	μΑ
current	2SB1548A		$V_{CE} = -60 \text{ V}, I_B = 0$			-300	
Emitter cutoff current		I _{EBO}	$V_{EB} = -5 V, I_C = 0$			-1	mA
Collector to emitter	2SB1548	V _{CEO}	$I_{\rm C} = -30 \text{ mA}, I_{\rm B} = 0$	-60			V
voltage	2SB1548A			-80			
Forward current transfe	er ratio	h _{FE1} *	$V_{CE} = -4 V, I_C = -1 A$	70		250	
		h _{FE2}	$V_{CE} = -4 V, I_C = -3 A$	10			
Base to emitter voltage	;	V_{BE}	$V_{CE} = -4 V, I_C = -3 A$			-1.8	V
Collector to emitter satu	ration voltage	V _{CE(sat)}	$I_{\rm C} = -3$ A, $I_{\rm B} = -0.375$ A			-1.2	V
Transition frequency		f_T	$V_{CE} = -10 \text{ V}, I_C = -0.5 \text{ A}, f = 10 \text{ MHz}$		30		MHz
Turn-on time		t _{on}	$I_{C} = -1 \text{ A}, I_{B1} = -0.1 \text{ A}, I_{B2} = 0.1 \text{ A}$		0.5		μs
Storage time		t _{stg}			1.2		μs
Fall time		t _f			0.3		μs

Note) *: Rank classification

Rank	Q	Р		
$\mathbf{h}_{\mathrm{FE1}}$	70 to 150	120 to 250		

Ordering can be made by the common rank (PQ rank $h_{FE1} = 70$ to 250) in the rank classification.



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